Effects of Sb on structure, micro structure and electrical characteristics of Sb-modified (K0.41Na0.59)NbO3 ceramics

Le Tran Uyen Tu*

University of Sciences, Hue University, 77 Nguyen Hue, Hue, Vietnam

* Correspondence to Le Tran Uyen Tu <tuletranuyen@hueuni.edu.vn> (*Received: 29 March 2023; Revised: 21 April 2023; Accepted: 28 May 2023*)

Abstract. Lead-free (Na0.59K0.41)(Nb1_{-x}Sb_x)O₃ ceramic ($x = 0 \div 0.12$) were prepared by the solid phase reaction method. The influence of Sb concentration on the structure, microstructure and electrical properties of the ceramic was studied. Results indicate that the presence of pure perovskite phase was revealed by XRD patterns recorded for the ceramics, which also showed a shift in structure from orthorhombic to mixed rhombohedral and tetragonal with an increase in x value. At x = 0.06, the ceramics express the best microstructure, the particles were tightly packed with an average particle size of 1.76 µm. The (Na0.59K0.41)(Nb0.94Sb0.06)O₃ ceramics have the best dielectric and ferroelectric properties: the ceramic density (ρ) is 4.48 g/cm³ (relative density: 98.7% of the theoretical value); highest dielectric constant at *T*c (ε_{max}) of 12031; dielectric constant at *RT* (ε) of 945; low dielectric loss (tanð) of 0.15; and high remanent polarization (P_r) of 11,2 µC/cm²; and the reactance field (E_c) of 8.7 kV/cm, and the phase transition temperatures (*T*c) of 372 °C, and (*T*o-T) of 157 °C.

Keywords: Lead free ceramics, Sb-doping, Dielectric response, ferroelectrical properties

1 Introduction

One of the most innovative new materials is ferroelectric ceramics, which is highly significant in a variety of technical fields. Due to lead oxide's toxicity and high vapor pressure during processing, which can pollute the environment, piezoceramic systems have been manufactured and primarily used for lead (PZT) based piezoelectric ceramics for many years [1-4]. Consequently, a great deal of basic and applied research has been carried out on lead-free piezoelectric ceramics [5-7]. Among them, (K, Na)NbO3 (KNN) based piezoelectric ceramics was the most interested because of its strong ferroelectricity and high Curie temperature (about 420 °C) [8, 9], thereby it has become one of the most promising candidates for replacing Pb-based ceramics. By using a template grain growth method, Li *et al.* [10] created textured KNN-based lead-free ceramics in 2018, which showed improved electrical properties like piezoelectric constant ($d_{33} \approx 700 \text{ pC/N}$) and electromechanical coupling factor ($k_P \approx 0.76$). Recently, a novel strategy is developed to construct the *R*-*T* phase boundary by adding an ABO₃-type component, which can tailor *T*_{R-0} and *T*_{O-T} to room temperature simultaneously, and is beneficial to establish the *R*-*T* phase boundary, leading to the improvement of piezoelectric properties in the KNN-based materials [4, 11].

Therefore, the $(K_{0.41}Na_{0.59})(Nb_{1-x}Sb_x)O_3$ combined with Sb element were introduced to stabilize the perovskite structure and form the *R*-*T* phase boundary in the KNN based ceramics. Our recent study's [12] findings indicate that lead-free $(K_{0.41}Na_{0.59})NbO_3$ ceramics had the best electrical characteristics ($\varepsilon = 470$, $k_p = 0.32$, $k_t = 0.5$, $d_{33} = 120$

pC/N, $P_r = 11.6 \ \mu$ C/cm²) were obtained. This study aimed to address the need for practical applications by examining the impact of (K_{0.41}Na_{0.59})NbO₃ lead-free.

2 Experimental section

The traditional mixed-oxide process was used to produce lead-free (K0.41Na0.59)(Nb1-xSbx)O3 (KNNS) ceramics with *x* = 0.0, 0.03, 0.06, 0.09, and 0.12. To lessen the impact of moisture, K2CO3, Na2CO3, Sb₂O₃, Ta₂O₅, and Nb₂O₅ (purity 99.9%) were used as the starting materials. K2CO3 and Na2CO3 powders were dried for two hours at 150 °C in an oven. After that, the powdered samples were weighed and milled for sixteen hours in ethanol. The sample was then calcined for two hours at 850 °C after being dried, pressed, and heated through two cycles of calcination. The calcined powders were then ball-milled for 20 h and compressed into disks (diameter: 12 mm; thickness: 1.5 mm) at a pressure of 1.5 T/cm² and sintered at 1090 °C for 2 h to produce KNNST ceramics.

The XRD (D8 ADVANCE) technique was used to determine the crystal structure of ceramics, and an SEM system (Hitachi S 4800) was used to assess the morphology and microstructure of the samples. The Archimedes method was used to calculate ceramic density, while the Sawyer-Tower method was used to examine ferroelectric hysteresis loops. The capacitance and dielectric loss of the ceramic samples (RLC HIOKI 3532) were measured using an impedance analyzer.

3 Results and discussion

The changes in the structure of the Sb-doped KNN ceramics containing different amounts of Sb are shown in Fig. 1. As shown in Fig. 1(a), a pure perovskite phase is observed. To study in more detail the phase structure of KNNS ceramics, the

XRD patterns investigated at $2\theta = 21-24^{\circ}$ (Fig. 1(b)) and $2\theta = 44-47^{\circ}$ (Fig. 1(c)), respectively. The ceramic's structure appears to change from an orthorhombic phase (O-phase) with two split peaks at (202)o, lower angle: (020)o; higher angle; $a \approx c > b$) to the tetragonal phase (*T*-phase) with $(200)_T/(002)_T$ peaks, as shown in Fig. 1(c). The change in phase structure of the (K0.41Na0.59)(Nb1xSbx)O3 ceramics could be attributed to the fact that the ionic radius of the Sb³⁺ (0.76 Å) or Sb⁵⁺ (0.62 Å) ions were comparable to the radius of the Nb⁵⁺ atoms (0.78 Å) in the B-site and smaller than the radii of atoms such as K⁺ (1.64 Å) and Na⁺ (1.32 Å) that are present in the A-site, as shown in the ABO₃ model [5, 20, 22–24]. The results agreed well with previously reported results Jiang et al. 0.9(K0.5Na0.5)(Nb1-xSbx)O3-[13] for 0.1Bi(Ni2/3Nb1/3)O3 and Nuraini et at. [14] for (K0.5Na0.5)NbO3 - Ba0.8Sr0.2TiO3 and Gio et al. [15] for (K0.48Na0.48Li0.04)(Nb0.95Sb0.05)O3 Bio.5(Nao.82Ko.18)0.5ZrO3.

Fig. 2 shows the microstructure of (K0.41Na0.59)(Nb1-xSbx)O3 ceramics sintered at 1090°C for 2 h. As can be seen in Fig. 2, the average grain size of the ceramics ranged from 0.67 to 2.39 µm, and all ceramics possessed prominent grain boundaries. Generally speaking, of Sb with the addition modifies the microstructure of KNNS ceramics. As illustrated in Fig. 2(f), the grain size increased as the Sb concentration rose and peaked at 2.39 μ m at x = 0.03. In the undoped KNN ceramic sample, the grain boundary is very clear, with many voids (Figure 2(a)), demonstrating low ceramic density (Fig. 3(a). The microstructure of the ceramic becomes denser, the grains are uniform, and the voids decrease with a ceramic pore size in the vessel of 1.76 µm (Figure 2(c). This is consistent with the increase in ceramic density with increasing Sb concentration. In other words, at x =0.06, the best microstructure, the sample with the most tightly packed particles and the fewest

voids, this is the sample with the highest ceramic density (4.46 g/cm³ (reaching 98.7% of the theoretical value) (Fig. 3(a)). In addition, with the increase of Sb concentration, the particle size decreased gradually and was smaller in the sample with x = 0.12 (Fig. 2(e)) with an average particle size of 0.81 µm. This is explained by the dissolution of Sb into the KNN lattice and

forming a homogeneous solid solution. That means that Sb³⁺ ions (0.76 Å) or Sb⁵⁺ ions (0.62 Å) penetrate the KNN lattice and substitute for Nb⁵⁺ ions (0.78 Å) at position B due to similar radii [16]. It is this Sb doping that is responsible for the increase in ceramic density by creating the perfect microstructure of ceramic [17].



Fig. 1. XRD patterns recorded for (K0.41Na0.59)(Nb1-xSbx)O3 ceramics under conditions of varying x



Fig. 2. Microstructures of $(K_{0.41}Na_{0.59})(Nb_{1-x}Sb_x)O_3$: a) x = 0,0; b) x = 0,03; c) x = 0,06; d) x = 0,09; e) x = 0,12; f) the average grain size of the semples

The dielectric loss $(\tan \delta)$ and room temperature dielectric constant (ε) of Sb-doped KNN ceramics are measured at a frequency of 1 kHz, as shown in Fig.3. The dielectric constant ε increases with the *x* increases and reaches the highest value (ε = 945) at *x* = 0.06. However, when *x* > 0.06, the dielectric constant ε decreased. Conversely, when the *x* increases, the value of the dielectric loss tan δ decreases to the smallest value (tan δ = 0.15) at *x* = 0.06, then increases. These may be related to the density and microstructure of ceramics. According to the work of Ullah et al. [18], the high ceramic density, the large grain size, and the perfect microstructure are responsible for the increased dielectric properties.

The dielectric constant (ε) and dielectric loss (tan δ), which were measured at 1 kHz, are shown to depend on temperature in Fig. 4(a). As seen, all the $\varepsilon(T)$ curves of the ceramic samples have two obvious peaks: a peak at low temperature, which is the peak corresponding to the orthorhombic-tetragonal ferroelectric phase transition temperature (*T*o-*T*), the second peak at higher temperatures, corresponding to the *T*c

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temperature (called the ferroelectric-paraelectric phase transition) [19]. From Fig. 4(b) shows that the addition of Sb has a negligible influence on the To-T phase transition temperatures and T_C of (K0.41Na0.59)(Nb1-xSbx)O3 ceramics. Thus, Sb doping has a significant effect on the Tc and To-T phase transition temperatures of ceramic (K0.41Na0.59)(Nb1xSbx)O3 and the values fluctuate in the range of 333–402 °C, and 150–250 °C, respectively. The $T_{\rm C}$ decreases but still maintains a high temperature when x = 0.06 ($T_{\rm C} = 371$ °C) while the quite low $T_{\rm O-T}$ of 157 °C. This result is consistent with the research results on the structure of ceramics and the similar with the result of [1-3] and Venet et al. [20]. Fig. 4(a) also shows that the peak of the sharp dielectric constant, indicating that the ceramics is a normal ferroelectric. The dielectric constant at T_{C} (ε_{max}) increases with the x increases and reaches the highest value ($\varepsilon_{max} = 12031$) at x = 0.06. However, when x > 0.06, the ε_{max} decreased (Fig. 4(b). This can be explained by the coexistence of the two R-Tphases, resulting in the MPB effect, which eventually results in an increase in the mobility of the domains [21, 22].



Fig. 3. (a) ceramic density; (b) dielectric constant and the dielectric loss of (K0.41Na0.59)(Nb1-xSbx)O3



Fig. 4. Temperature-dependent dielectric constant and dielectric loss of (K0.41Na0.59)(Nb1-xSbx)O3 at 1 kHz

Fig. 5(a) shows the shapes of *P*-*E* ferroelectric hysteresis loops measured at room temperature of the (K_{0.41}Na_{0.59})(Nb_{1-x}Sb_x)O₃ ceramic samples. As shown in figure 5(a-b), the Sb addition has an obvious influence on the ferroelectric properties of the ceramics. A round-shaped *P*–*E* hysteresis loop is obtained for the ceramics well-saturated *P*–*E* hysteresis loops are observed, showing good ferroelectric properties. The value of *P*_r increases with an increase in *x* and reaches the maximum value of 11.2 μ C/cm² at *x* = 0.06, and then decreases. The *E*_c values decrease with an increase *x* and reach the minimum value of 6.7 kV/cm at *x* = 0.12, while *E*_c reaches the

maximum value of 8.7 kV/cm at x = 0.06. The ferroelectric improvement in properties is attributed to the MPB effect, which results in the improvement in the orientation directions of the domains. It is thought that the perfect microstructure, small grain boundaries, and high ceramic density have improved the polarization of Sb-doped KNN ceramics. As previously discussed, the grain size and density increased with the increase in the Sb content, which helped improve the polarization of the ferroelectric ceramics. Similar findings have been published before [23], and they are consistent with the ceramics' studied dielectric characteristics.



Fig. 5. Ferroelectric behavior of (K_{0.41}Na_{0.59})(Nb_{1-x}Sb_x)O₃ ceramics: (a) P–E hysteresis; (b) P_r and E_c values versus Sb contents

KNN-based ceramics	Density g/cm ³	Pr (μC/cm²)	Ec (kv/cm)	Тс (⁰С)	То-т (ºС)	Е	Ref.
(Na0.59K0.41)(Nb0.94Sb0.06)O3	4.48	11.2	6.7	372	157	945	This work
(K0.41Na0.59)NbO3	4.36	11.6	6.7	404	238	470	[12]
[Na0.5K0.5]0.95(Li)0.05(Sb)0.05(Nb)0.95O3	4.39	6.6	23.8	339	100	800	[24]
K0.475Na0.525)NbO3	4.31	10.5	11.1	425	217	450	[25]

4.25

Table 1. Compilation of physical properties for the KNN-based ceramics with the other reported data

The KNN-based ceramics reported to date [12, 24-26] as listed in Table 1. Our results indicated that the $(Na_{0.59}K_{0.41})(Nb_{0.94}Sb_{0.06})O_3$ ceramics can be obtained at a lower sintering temperature (1090 $^{\circ}C$), while the dielectric and ferroelectric properties of the material ceramics are wellmaintained.

(Na1-xKx)NbO3

4 Conclusions

The traditional mixed-oxide process was used to produce lead-free (K0.41Na0.59)(Nb1-xSbx)O3 (KNNS) ceramics with *x* = 0.0, 0.03, 0.06, 0.09, and 0.12. The results show that all samples have pure perovskite shifts from the phase and orthorhombic structure to the mixed rhombohedral and tetragonal structure with an increase in the *x* value. With the x = 0.06, physical properties of $(Na_{0.59}K_{0.41})(Nb_{0.94}Sb_{0.06})O_3$ ceramics are best: the density of 4.48 g/cm³; the dielectric constant (ϵ) of 945; the dielectric loss (tan δ) of 0.15; the remanent polarization (P_r) of 11.2 μ C/cm², and the reactance field (E_c) of 8.7 kV/cm, and the phase transition temperatures (T_c) of 372 °C, (T_{0-T}) of 157 °C.

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[26]

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